

BC557

Switching and Amplifier

- High Voltage: BC556, V_{CEO}= -65V
- Low Noise: BC559, BC560
- Complement to BC546 ... BC 550



1. Collector 2. Base 3. Emitter

PNP Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CBO}	Collector-Base Voltage			
020	: BC556	-80	V	
	: BC557/560	-50	V	
	: BC558/559	-30	V	
V _{CEO}	Collector-Emitter Voltage			
	: BC556	-65	V	
	: BC557/560	-45	V	
	: BC558/559	-30	V	
V_{EBO}	Emitter-Base Voltage	-5	V	
I _C	Collector Current (DC)	-100	mA	
P _C	Collector Power Dissipation	500	mW	
TJ	Junction Temperature	150	°C	
T _{STG}	Storage Temperature	-65 ~ 150	°C	

Electrical Characteristics T_a=25°C unless otherwise noted

		T		T		
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off Current	V_{CB} = -30V, I_{E} =0			-15	nA
h _{FE}	DC Current Gain	V _{CE} = -5V, I _C =2mA	110		800	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = -10mA, I _B = -0.5mA I _C = -100mA, I _B = -5mA		-90 -250	-300 -650	mV mV
V _{BE} (sat)	Collector-Base Saturation Voltage	I_{C} = -10mA, I_{B} = -0.5mA I_{C} = -100mA, I_{B} = -5mA		-700 -900		mV mV
V _{BE} (on)	Base-Emitter On Voltage	V_{CE} = -5V, I_{C} = -2mA V_{CE} = -5V, I_{C} = -10mA	-600	-660	-750 -800	mV mV
f _T	Current Gain Bandwidth Product	V_{CE} = -5V, I_{C} = -10mA, f=10MHz		150		MHz
C _{ob}	Output Capacitance	V _{CB} = -10V, I _E =0, f=1MHz			6	pF
NF	Noise Figure : BC556/557/558	V _{CE} = -5V, I _C = -200μA		2	10	dB
	: BC559/560	$f=1KHz$, $R_G=2K\Omega$		1	4	dB
	: BC559	$V_{CE} = -5V, I_{C} = -200\mu A$		1.2	4	dB
	: BC560	$R_G = 2K\Omega$, $f = 30 \sim 15000$ MHz		1.2	2	dB

h_{FE} Classification

Classification	Α	В	С
h _{FE}	110 ~ 220	200 ~ 450	420 ~ 800

Typical Characteristics

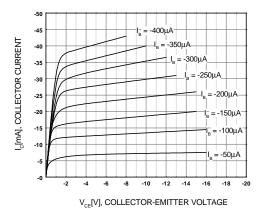


Figure 1. Static Characteristic

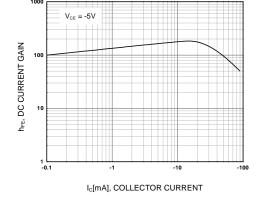


Figure 2. DC current Gain

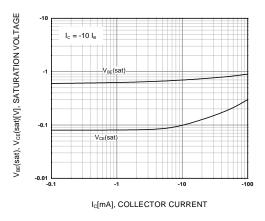


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

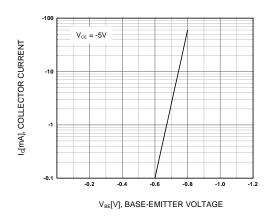


Figure 4. Base-Emitter On Voltage

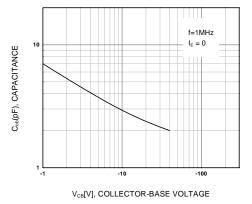


Figure 5. Collector Output Capacitance

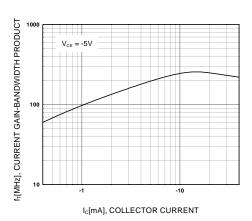
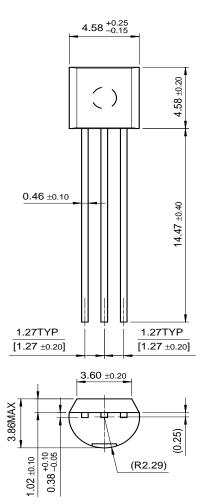
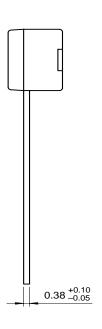


Figure 6. Current Gain Bandwidth Product

Package Dimensions

TO-92





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Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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